



BUK761R6-40E

N-channel TrenchMOS standard level FET

5 September 2013

Product data sheet

1. General description

Standard level N-channel MOSFET in a SOT404A package using TrenchMOS technology. This product has been designed and qualified to AEC Q101 standard for use in high performance automotive applications.

2. Features and benefits

- AEC Q101 compliant
- Repetitive avalanche rated
- Suitable for thermally demanding environments due to 175 °C rating
- True standard level gate with $V_{GS(th)}$ rating of greater than 1 V at 175 °C

3. Applications

- 12 V Automotive systems
- Electric and electro-hydraulic power steering
- Motors, lamps and solenoid control
- Start-Stop micro-hybrid applications
- Transmission control
- Ultra high performance power switching

4. Quick reference data

Table 1. Quick reference data

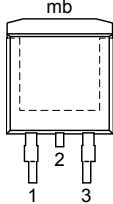
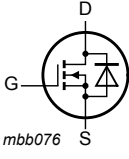
| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|--------------------------------|----------------------------------|--|-----|------|------|------|
| V_{DS} | drain-source voltage | $T_j \geq 25\text{ °C}; T_j \leq 175\text{ °C}$ | - | - | 40 | V |
| I_D | drain current | $V_{GS} = 10\text{ V}; T_{mb} = 25\text{ °C};$ Fig. 1 | [1] | - | 120 | A |
| P_{tot} | total power dissipation | $T_{mb} = 25\text{ °C};$ Fig. 2 | - | - | 349 | W |
| Static characteristics | | | | | | |
| $R_{DS(on)}$ | drain-source on-state resistance | $V_{GS} = 10\text{ V}; I_D = 25\text{ A}; T_j = 25\text{ °C};$ Fig. 11 | - | 1.3 | 1.57 | mΩ |
| Dynamic characteristics | | | | | | |
| Q_{GD} | gate-drain charge | $V_{GS} = 10\text{ V}; I_D = 25\text{ A}; V_{DS} = 32\text{ V};$ Fig. 13 ; Fig. 14 | - | 48.2 | - | nC |

[1] Continuous current is limited by package.



5. Pinning information

Table 2. Pinning information

| Pin | Symbol | Description | Simplified outline | Graphic symbol |
|-----|--------|-----------------------------------|---|---|
| 1 | G | gate |  <p>D2PAK (SOT404A)</p> |  |
| 2 | D | drain | | |
| 3 | S | source | | |
| mb | D | mounting base; connected to drain | | |

6. Ordering information

Table 3. Ordering information

| Type number | Package | | |
|--------------|---------|--|---------|
| | Name | Description | Version |
| BUK761R6-40E | D2PAK | plastic single-ended surface-mounted package (D2PAK); 3 leads (one lead cropped) | SOT404A |

7. Marking

Table 4. Marking codes

| Type number | Marking code |
|--------------|--------------|
| BUK761R6-40E | BUK761R6-40E |

8. Limiting values

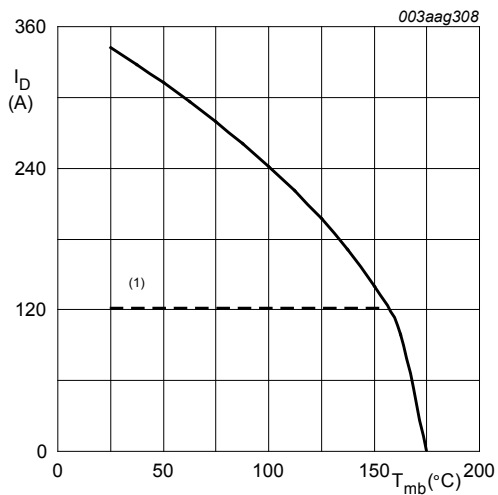
Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | | Min | Max | Unit |
|-----------|-------------------------|---|-----|-----|------|------|
| V_{DS} | drain-source voltage | $T_j \geq 25\text{ °C}$; $T_j \leq 175\text{ °C}$ | | - | 40 | V |
| V_{DGR} | drain-gate voltage | $R_{GS} = 20\text{ k}\Omega$ | | - | 40 | V |
| V_{GS} | gate-source voltage | $T_j \leq 175\text{ °C}$; DC | | -20 | 20 | V |
| I_D | drain current | $T_{mb} = 25\text{ °C}$; $V_{GS} = 10\text{ V}$; Fig. 1 | [1] | - | 120 | A |
| | | $T_{mb} = 100\text{ °C}$; $V_{GS} = 10\text{ V}$; Fig. 1 | [1] | - | 120 | A |
| I_{DM} | peak drain current | $T_{mb} = 25\text{ °C}$; pulsed; $t_p \leq 10\text{ }\mu\text{s}$; Fig. 4 | | - | 1355 | A |
| P_{tot} | total power dissipation | $T_{mb} = 25\text{ °C}$; Fig. 2 | | - | 349 | W |
| T_{stg} | storage temperature | | | -55 | 175 | °C |
| T_j | junction temperature | | | -55 | 175 | °C |

| Symbol | Parameter | Conditions | | Min | Max | Unit |
|-----------------------------|--|--|--------|-----|------|------|
| Source-drain diode | | | | | | |
| I_S | source current | $T_{mb} = 25\text{ }^\circ\text{C}$ | [1] | - | 120 | A |
| I_{SM} | peak source current | pulsed; $t_p \leq 10\text{ }\mu\text{s}$; $T_{mb} = 25\text{ }^\circ\text{C}$ | | - | 1355 | A |
| Avalanche ruggedness | | | | | | |
| $E_{DS(AL)S}$ | non-repetitive drain-source avalanche energy | $I_D = 120\text{ A}$; $V_{sup} \leq 40\text{ V}$; $R_{GS} = 50\text{ }\Omega$; $V_{GS} = 10\text{ V}$; $T_{j(\text{init})} = 25\text{ }^\circ\text{C}$; unclamped; Fig. 3 | [2][3] | - | 1008 | mJ |

- [1] Continuous current is limited by package.
- [2] Single-pulse avalanche rating limited by maximum junction temperature of 175 °C.
- [3] Refer to application note AN10273 for further information.



(1) Capped at 120A due to package

Fig. 1. Continuous drain current as a function of mounting base temperature

$$V_{GS} \geq 10V$$

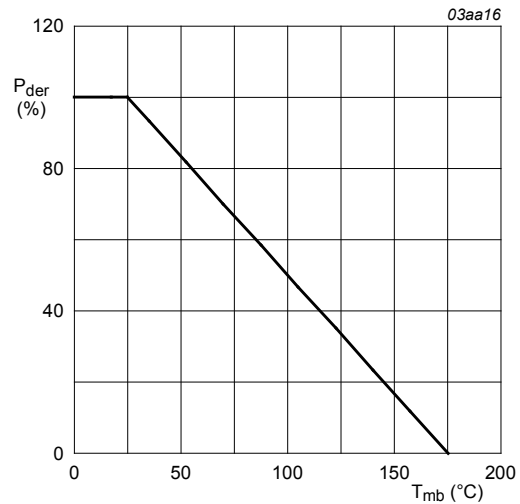


Fig. 2. Normalized total power dissipation as a function of mounting base temperature

$$P_{der} = \frac{P_{tot}}{P_{tot(25^\circ\text{C})}} \times 100\%$$

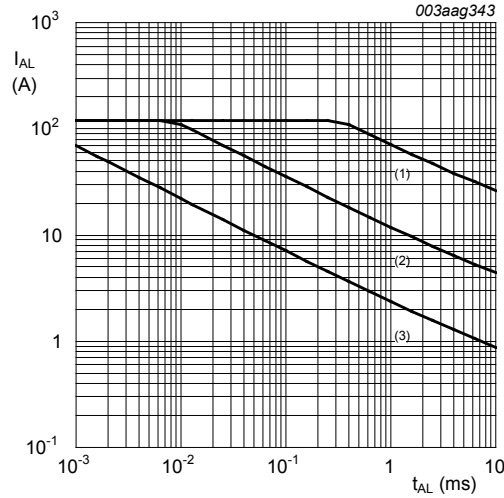


Fig. 3. Single-pulse and repetitive avalanche rating; avalanche current as a function of avalanche time

(1) $T_{j (init)} = 25^{\circ}C$; (2) $T_{j (init)} = 150^{\circ}C$; (3) Repetitive Avalanche

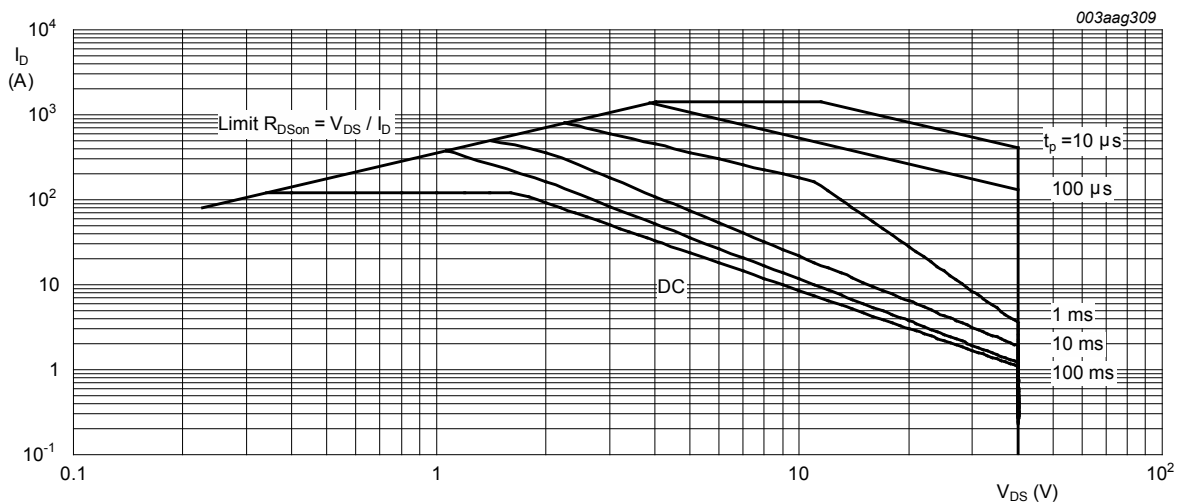


Fig. 4. Safe operating area; continuous and peak drain currents as a function of drain-source voltage

$T_{mb} = 25^{\circ}C$; I_{DM} is a single pulse

9. Thermal characteristics

Table 6. Thermal characteristics

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|----------------|---|--|-----|-----|------|------|
| $R_{th(j-mb)}$ | thermal resistance from junction to mounting base | Fig. 5 | - | - | 0.43 | K/W |
| $R_{th(j-a)}$ | thermal resistance from junction to ambient | minimum footprint ; mounted on a printed-circuit board | - | 50 | - | K/W |

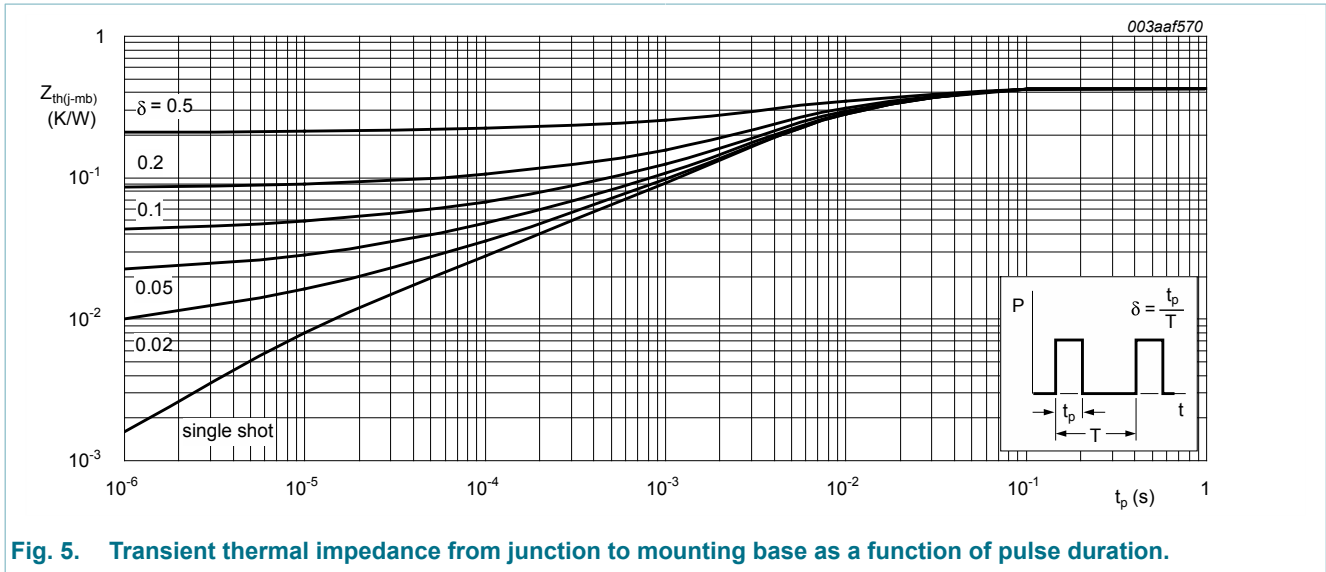


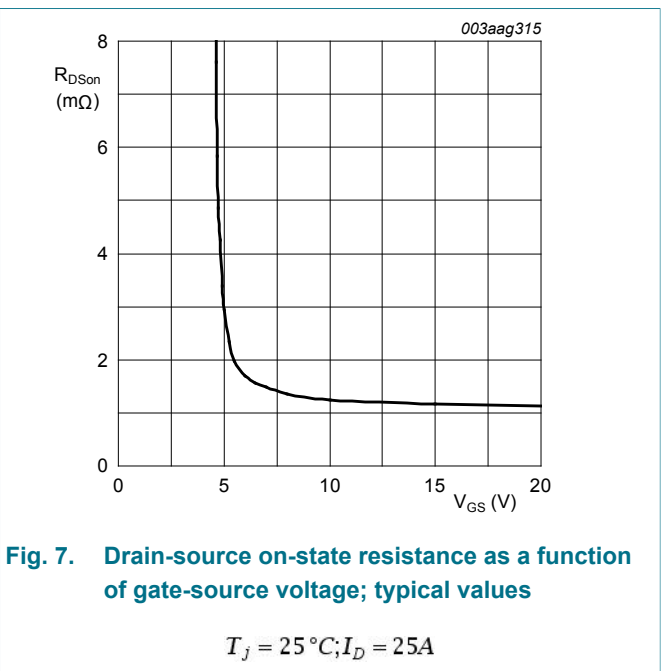
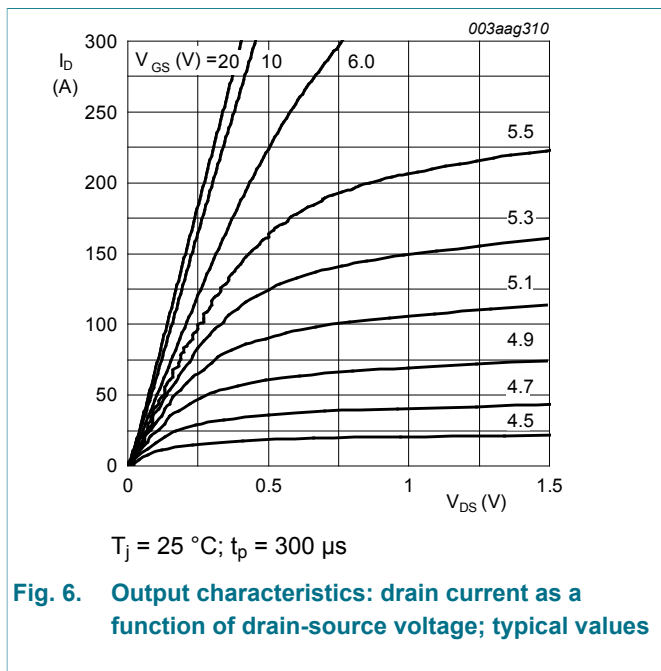
Fig. 5. Transient thermal impedance from junction to mounting base as a function of pulse duration.

10. Characteristics

Table 7. Characteristics

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|--------------------------------|----------------------------------|--|-----|------|------|------------|
| Static characteristics | | | | | | |
| $V_{(BR)DSS}$ | drain-source breakdown voltage | $I_D = 250 \mu A; V_{GS} = 0 V; T_j = 25 \text{ }^\circ C$ | 40 | - | - | V |
| | | $I_D = 250 \mu A; V_{GS} = 0 V; T_j = -55 \text{ }^\circ C$ | 36 | - | - | V |
| $V_{GS(th)}$ | gate-source threshold voltage | $I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = 25 \text{ }^\circ C;$ Fig. 9; Fig. 10 | 2.4 | 3 | 4 | V |
| | | $I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = -55 \text{ }^\circ C;$ Fig. 10 | - | - | 4.5 | V |
| | | $I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = 175 \text{ }^\circ C;$ Fig. 10 | 1 | - | - | V |
| I_{DSS} | drain leakage current | $V_{DS} = 40 \text{ V}; V_{GS} = 0 \text{ V}; T_j = 25 \text{ }^\circ C$ | - | 0.25 | 2 | μA |
| | | $V_{DS} = 40 \text{ V}; V_{GS} = 0 \text{ V}; T_j = 175 \text{ }^\circ C$ | - | - | 500 | μA |
| I_{GSS} | gate leakage current | $V_{GS} = 20 \text{ V}; V_{DS} = 0 \text{ V}; T_j = 25 \text{ }^\circ C$ | - | 2 | 100 | nA |
| | | $V_{GS} = -20 \text{ V}; V_{DS} = 0 \text{ V}; T_j = 25 \text{ }^\circ C$ | - | 2 | 100 | nA |
| R_{DSon} | drain-source on-state resistance | $V_{GS} = 10 \text{ V}; I_D = 25 \text{ A}; T_j = 25 \text{ }^\circ C;$ Fig. 11 | - | 1.3 | 1.57 | m Ω |
| | | $V_{GS} = 10 \text{ V}; I_D = 25 \text{ A}; T_j = 175 \text{ }^\circ C;$ Fig. 12; Fig. 11 | - | - | 3 | m Ω |
| Dynamic characteristics | | | | | | |
| $Q_{G(tot)}$ | total gate charge | $I_D = 25 \text{ A}; V_{DS} = 32 \text{ V}; V_{GS} = 10 \text{ V};$ Fig. 13; Fig. 14 | - | 145 | - | nC |
| Q_{GS} | gate-source charge | | - | 35.7 | - | nC |
| Q_{GD} | gate-drain charge | | - | 48.2 | - | nC |

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|---------------------------|------------------------------|---|-----|------|-------|------|
| C_{iss} | input capacitance | $V_{GS} = 0\text{ V}; V_{DS} = 25\text{ V}; f = 1\text{ MHz};$ | - | 8500 | 11340 | pF |
| C_{oss} | output capacitance | $T_j = 25\text{ }^\circ\text{C};$ Fig. 15 | - | 1620 | 1950 | pF |
| C_{rss} | reverse transfer capacitance | | - | 985 | 1350 | pF |
| $t_{d(on)}$ | turn-on delay time | $V_{DS} = 30\text{ V}; R_L = 1.2\text{ }\Omega; V_{GS} = 10\text{ V};$ | - | 42 | - | ns |
| t_r | rise time | $R_{G(ext)} = 5\text{ }\Omega$ | - | 60 | - | ns |
| $t_{d(off)}$ | turn-off delay time | | - | 121 | - | ns |
| t_f | fall time | | - | 83 | - | ns |
| L_D | internal drain inductance | from upper edge of drain mounting base to center of die | - | 2.5 | - | nH |
| L_S | internal source inductance | from source lead to source bonding pad | - | 7.5 | - | nH |
| Source-drain diode | | | | | | |
| V_{SD} | source-drain voltage | $I_S = 25\text{ A}; V_{GS} = 0\text{ V}; T_j = 25\text{ }^\circ\text{C};$ Fig. 16 | - | 0.77 | 1.2 | V |
| t_{rr} | reverse recovery time | $I_S = 20\text{ A}; di_S/dt = -100\text{ A}/\mu\text{s}; V_{GS} = 0\text{ V};$ | - | 56 | - | ns |
| Q_r | recovered charge | $V_{DS} = 25\text{ V}$ | - | 94 | - | nC |



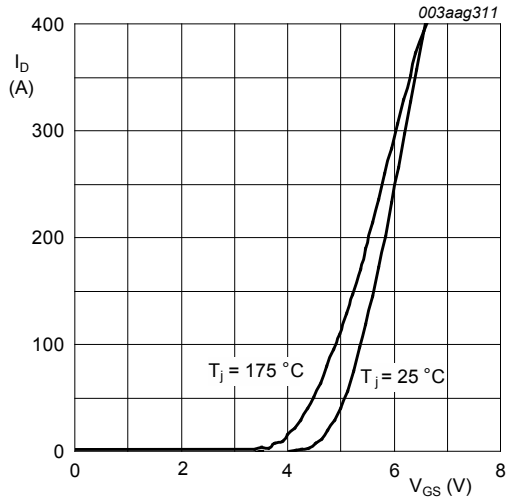


Fig. 8. Transfer characteristics: drain current as a function of gate-source voltage; typical values

$V_{DS} = 12 V$

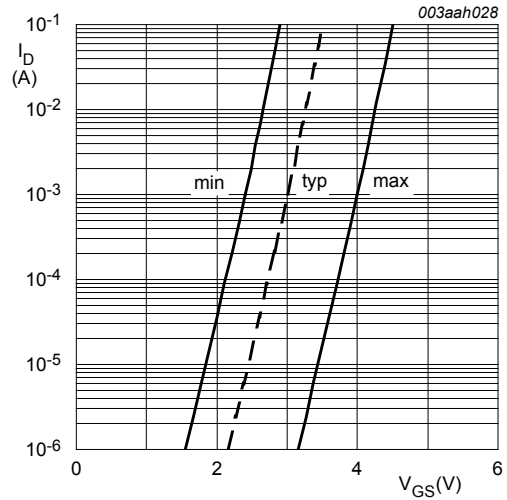


Fig. 9. Sub-threshold drain current as a function of gate-source voltage

$T_j = 25 °C; V_{DS} = 5 V$

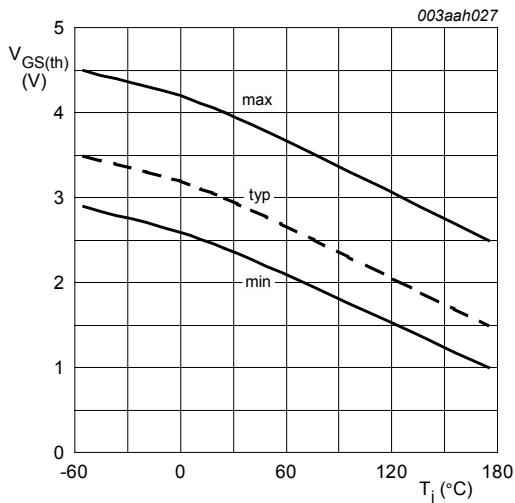


Fig. 10. Gate-source threshold voltage as a function of junction temperature

$I_D = 1 mA; V_{DS} = V_{GS}$

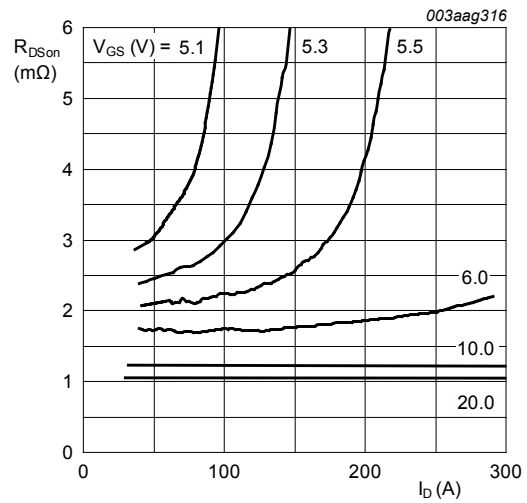


Fig. 11. Drain-source on-state resistance as a function of drain current; typical values

$T_j = 25 °C; t_p = 300 \mu s$

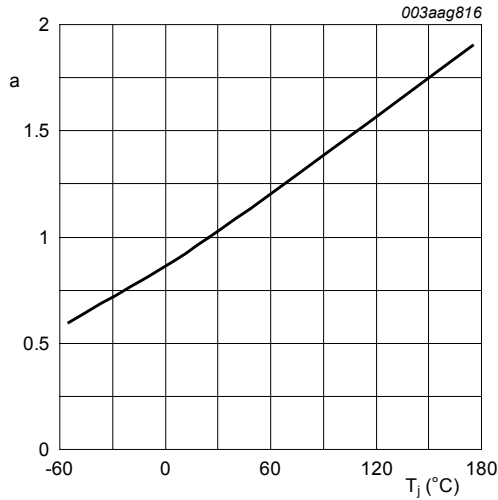


Fig. 12. Normalized drain-source on-state resistance factor as a function of junction temperature

$$a = \frac{R_{DS(on)}}{R_{DS(on)(25\text{ }^\circ\text{C})}}$$



Fig. 13. Gate charge waveform definitions

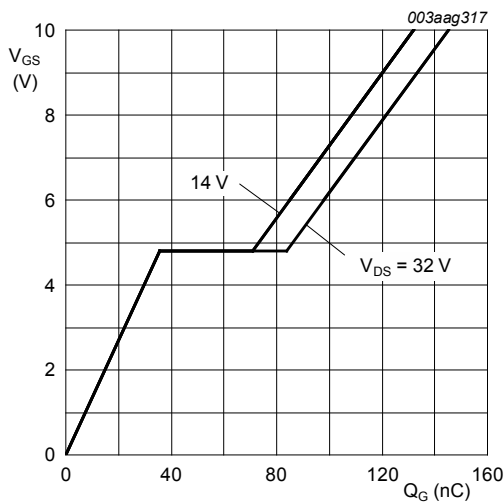


Fig. 14. Gate-source voltage as a function of gate charge; typical values

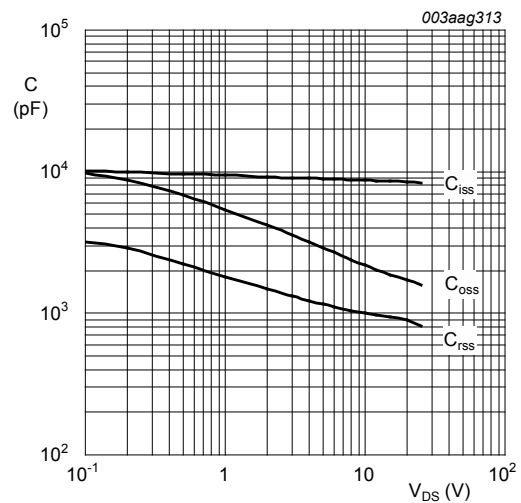
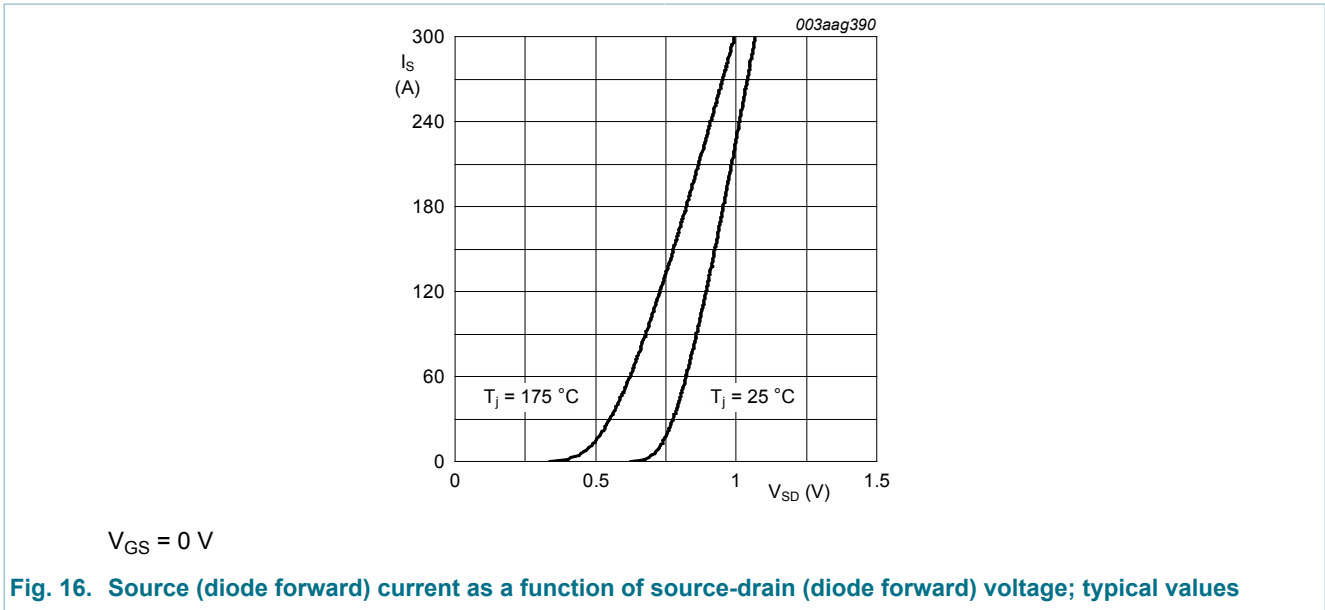
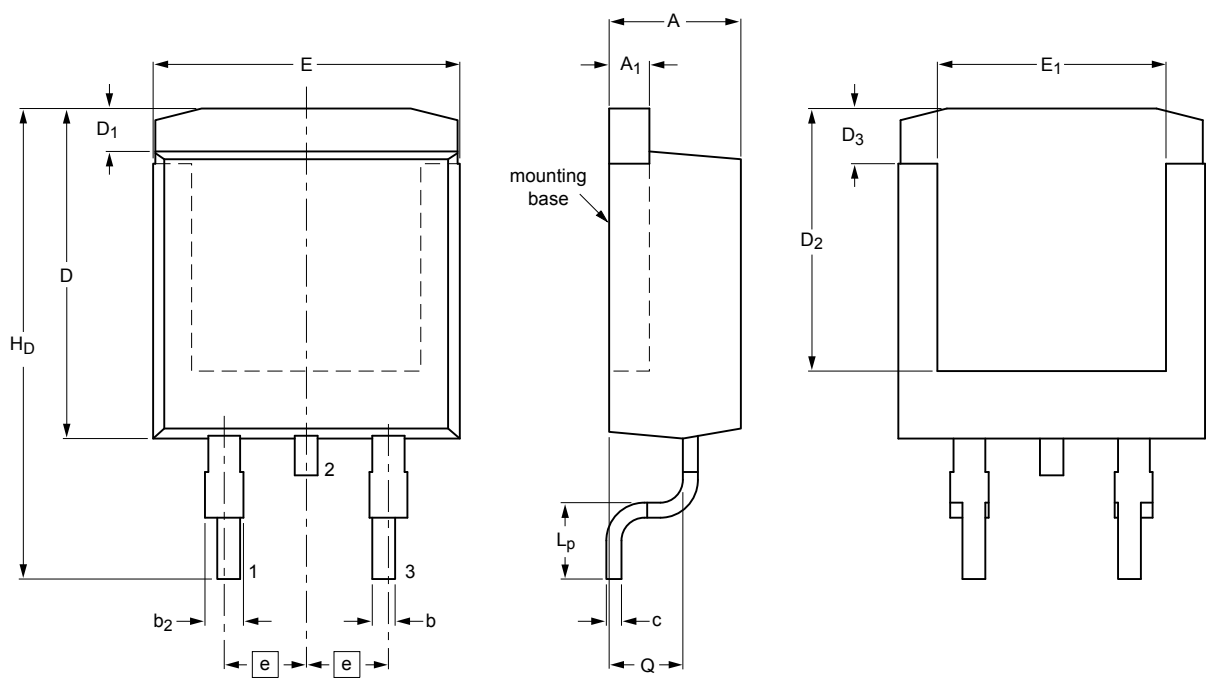


Fig. 15. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values



11. Package outline

Plastic single-ended surface-mounted package (D2PAK); 3 leads (one lead cropped) SOT404A



Dimensions (mm are the original dimensions)

| Unit | A | A ₁ | b | b ₂ | c | D _{max} | D ₁ | D ₂ | D ₃ | E | E ₁ | e | H _D | L _p | Q |
|------|-----|----------------|------|----------------|------|------------------|----------------|----------------|----------------|------|----------------|------|----------------|----------------|-----|
| max | 4.5 | 1.40 | 0.85 | 1.45 | 0.64 | 11 | 1.6 | 8.6 | 1.85 | 10.3 | 8.1 | | 15.8 | 2.9 | 2.6 |
| nom | | | | | | | | | | | | 2.54 | | | |
| min | 4.1 | 1.27 | 0.60 | 1.05 | 0.46 | | 1.2 | 8.0 | 1.40 | 9.7 | 7.6 | | 14.8 | 2.1 | 2.2 |

sot404a_po

| Outline version | References | | | | European projection | Issue date |
|-----------------|------------|-------|-------|--|---------------------|---------------------------------|
| | IEC | JEDEC | JEITA | | | |
| SOT404A | | | | | | 13-02-28 13-03-12 |

Fig. 17. Package outline D2PAK (SOT404A)

12. Legal information

12.1 Data sheet status

| Document status [1][2] | Product status [3] | Definition |
|--------------------------------|--------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

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